



Progress in STED-inspired sub-diffractive lithography of epoxides

A. Mikhailenko*, S. Islam, G.Gvindzhilia*, T.A.Klar*

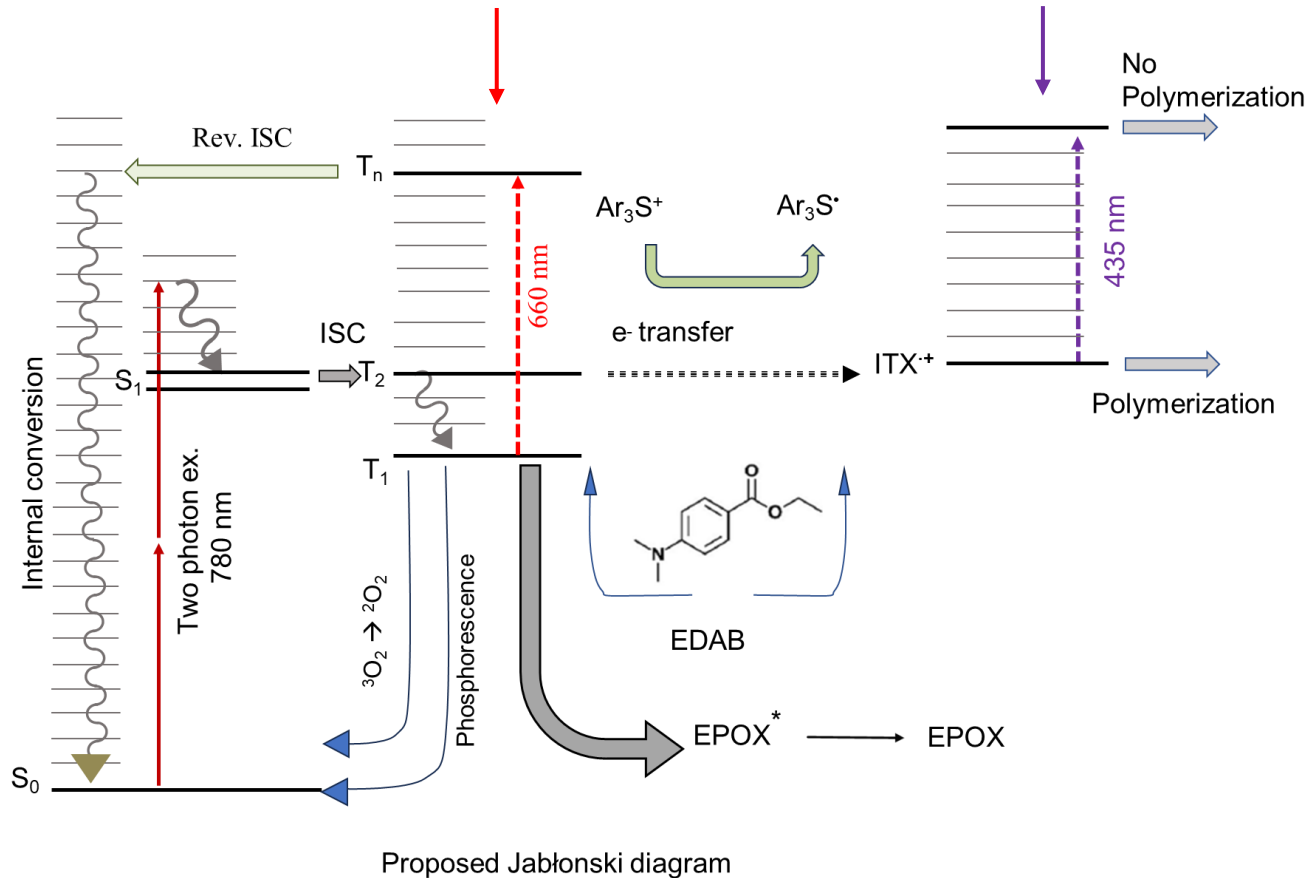
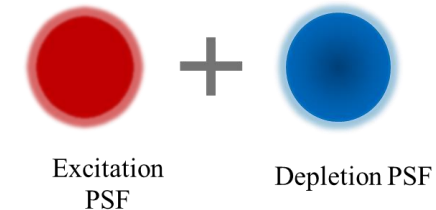
[*anastasiia.mikhailenko@jku.at](mailto:anastasiia.mikhailenko@jku.at), [*thomas.klar@jku.at](mailto:thomas.klar@jku.at)

Institute of Applied Physics and Linz Institute of Technology (LIT),
Johannes Kepler University Linz, Austria

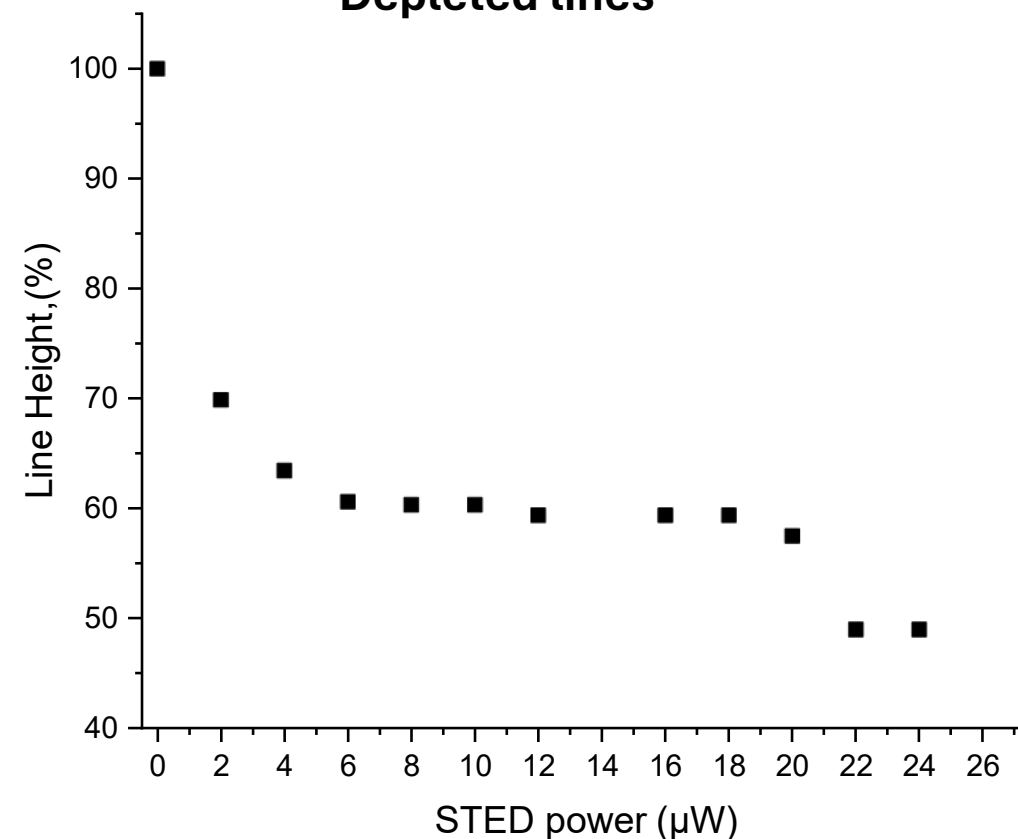
- **Motivation: STED-inspired multiphoton lithography (MPL)** has improved radical polymerization but remained unexplored for **cationic systems like epoxides**.
- **Goal:** Demonstrate **high-resolution lithography** using ITX-based photoresists with a quenching agent and an alternative depletion mechanism, achieving feature sizes comparable to those obtained in acrylate polymerization.

previously (see Poster Islam, Klar)

now: quenching of ITX radical ion



Depleted lines



Photochemistry:

- **Monomer:** 3,4-epoxycyclohexylmethyl 3,4-epoxycyclohexanecarboxylate (EPOX)
- **Photo-initiator:** Triarylsulfonium hexafluoroantimonate salt
- **Photosensitizer:** 2-Isopropylthioxanthone (ITX)

- Two step narrowing of linewidth
- Only 10 μW of 435 nm laser light needed (instead of 10 mW as in case of 660 nm)

